

## 13-MEMORY TONE/PULSE DIALER WITH HANDFREE AND HOLD FUNCTIONS

#### **GENERAL DESCRIPTION**

The W91350N series are tone/pluse switchable telephone dialers with thirteen memories, hold function, and a handfree dialing control circuit. Fabricated using CMOS technology, the W91350N series offer good performance in low-voltage and low-power applications.

#### FEATURES

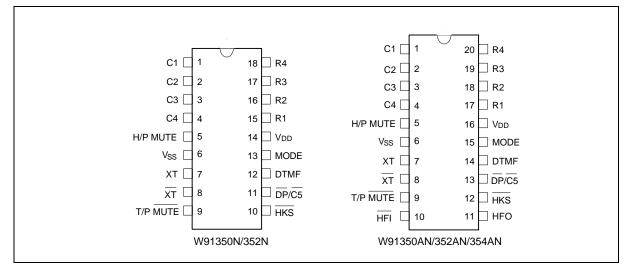
- DTMF/pulse switchable dialer
- Two by 32-digit redial memory and save memory
- Three by 16-digit one-touch direct repertory memory
- Ten by 16-digit two-touch direct repertory memory
- · Cascaded dialing allowed, with unlimited dialing length
- Pulse-to-tone (\*/T) keypad for long distance call operation
- Uses 5 × 5 keyboard
- Easy operation with redial, flash, pause, and \*/T keypads
- Pause,  $P \rightarrow T$  (pulse-to-tone) can be stored as a digit in memory
- Dialing rate (10 ppS or 20 ppS) is selectable by bonding option
- On-hook debounce time: 150 msec.
- Minimum tone output duration: 93 msec. (W91354AN: 87 mS)
- Minimum intertone pause: 93 msec. (W91354AN: 87 mS)
- Flash break time (73, 100, 300, 600 msec) selectable by keypad; pause time is 1.0 sec.
- Make/break ratio (40:60 or 33.3:66.7) selectable by MODE pin
- On-chip power-on reset
- Uses 3.579545 MHz crystal or ceramic resonator
- Packaged in 18 or 20-pin plastic DIP
- The different dialers in the W91350N series are shown in the following table:

TYPE NO.	REPLACEMENT TYPE NO.	PULSE (ppS)	FLASH (mS)	M/B	HANDFREE DIALING	PACKAGE (PINS)
W91350N	W91350	10	600/300/73/100	Pin	-	18
	W91351					
W91352N	W91352	20	600/300/73/100	Pin	-	18
W91350AN	W91350A	10	600/300/73/100	Pin	Yes	20
	W91351A					
W91352AN	W91352A	20	600/300/73/100	Pin	Yes	20
W91354AN	New type	10	600/300/73/100	Pin	Yes	20

Note: The W91354AN is for use in France only. The pause time is not added in pulse-to-tone function mode.



#### **PIN CONFIGURATIONS**



#### **PIN DESCRIPTION**

SYMBOL	18-PIN	20-PIN	I/O	FUNCTION
Column- Row Inputs	1–4 & 15–18	1–4 & 17–20	I	The keyboard inputs may be used with either a standard $5 \times 5$ keyboard or an inexpensive single contact (Form A) keyboard. Electronic input from a $\mu$ C can also be used. A valid key in is defined as a single row being connected to a single column.
XT, XT	7, 8	7, 8	I, O	A built-in inverter provides oscillation with an inexpensive 3.579545 MHz crystal or ceramic resonator.
T/P MUTE	9	9	0	The T/P MUTE is a conventional CMOS N-channel open drain output. The output transistor is switched on during dialing sequence and flash break time. Otherwise, it is switched off.
MODE	13	15	I	Pulling mode pin to Vss places the dialer in tone mode.
				Pulling mode pin to VDD places the dialer in pulse mode with M/B ratio of 40:60 (10 ppS, except for W91352N/352AN = 20 ppS). Floating mode pin places the dialer in pulse mode with M/B ratio of 33.3:66.7 (10 ppS, except for W91352N/352AN = 20 ppS).
HKS	10	12	I	Hook switch input. HKS = VDD: On-hook state. Chip in sleeping mode, no operation. HKS = Vss: Off-hook state. Chip is enabled for normal operation. HKS pin is pulled to VDD by an internal resistor.

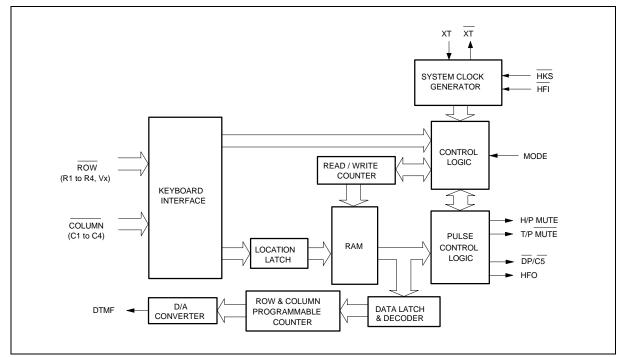


Pin Description, continued

SYMBOL	18-PIN	20-PIN	I/O				FL	JNCT	ON		
DP/C5	11	13	0	N-cha	N-channel open drain dialing pulse output.						
					Flash key will cause $\overline{DP}/\overline{C5}$ to be active in either tone mode or pulse mode.						
				The ti	The timing diagram for pulse mode is shown in Figure 1(a, b, c).						
Vdd, Vss	14, 6	16, 6	I	Powe	Power input pins.						
DTMF	12	14	0	In tor	In pulse mode, this pin remains in low state at all times. In tone mode, it will output a dual or single tone. Detailed timing diagram for tone mode is shown in Figure 2(a, b, c).						
					Out	put Freq	uency				
					Specified	I Act	ual	Erro	r %		
				R1	697	69	99	+0.2	28		
				R2	770	76	66	-0.5	2		
				R3	852	84	48	-0.4	7		
				R4 941 948 +0.74							
				C1 1209 1216 +0.57							
				C2	1336	13	332	-0.3	0		
				C3	1477	14	172	-0.3	4		
HFI, HFO	-	10, 11	I, O	Handfree control pins. The handfree control state is toggled on by a low pulse on the HFI input pin. The status of the handfree control state is described in the following table: CURRENT STATE NEXT STATE							
					k SW.	HFO	Inpu		HFO	Dialing	
					_	Low			High	Yes	
				On	Hook	High	HF	Ī	Low	No	
				Of	f Hook	High	HF	Ī	Low	Yes	
				On	Hook	_	Off	Hook	Low	Yes	
				Of	f Hook	Low	On I	Hook	Low	No	
				Of	f Hook	High	On H	Hook	High	Yes	
					oin is pulle led timing						
H/P MUTE	5	5	0	pulse	Detailed timing diagram is shown in Figure 3. The H/P MUTE is a conventional inverter output. During pulse dialing, flash break or hold period, this output is active high; otherwise, it remains in low state.						



#### **BLOCK DIAGRAM**



#### FUNCTIONAL DESCRIPTION

#### **Keyboard Operation**

C1	C2	C3	C4	$\overline{\text{DP}}/\overline{\text{C5}}$	
1	2	3	S	M1	R1
4	5	6	F4	M2	R2
7	8	9	Α	M3	R3
*/T	0	#	R/P	SAVE	R4
F1	F2	F3	Н		Vx

- S: Store function key
- H: Hold function key
- A: Indirect repertory memory dialing function key
- R/P: Redial and pause function key
- SAVE: Save function key
- \*/T: \* in tone mode and P $\rightarrow$ T in pulse mode
- M1, ..., M3: One-touch memory
- F1, ..., F4: Flash keys, F1 = 600 mS, F2 = 300 mS, F3 = 73 mS, F4 = 100 mS

Notes:

D1, ..., Dn, D1', ..., Dn': 0, ..., 9, \*/T, # Mn: M1 , ..., M3 ; Ln: 0, ..., 9; Fn: F1, ..., F4



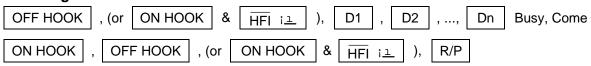
#### **Normal Dialing**



1. D1, D2, ..., Dn will be dialed out.

2. Dialing length is unlimited, but redial is inhibited if length exceeds 32 digits in normal dialing.

#### Redialing



- 1. The redial memory content will be dialed out.
- 2. The R/P key can execute the redial function only as the first key-in after off-hook; otherwise, it executes pause function.
- 3. If redialing length exceeds 32 digits, the redialing function will be inhibited.

#### Number Store

OFF HOOK         , (or         ON HOOK         & HFI         i         ),         D1         ,         D2         ,         ,         S
Mn (or Ln )
1. If the sequence of the dialed digits D1, D2,, Dn has not finished, S will be ignored. 2. D1, D2,, Dn will be dialed out and stored in memory location.
OFF HOOK , (or ON HOOK & HFI il ), S , D1 , D2 ,, Dn , S ,
Mn (or Ln )
3. D1, D2,, Dn will be stored in memory location but will not be dialed out.
4. R/P and $*/T$ keys can be stored as a digit in memory.
In store mode, R/P is the pause function key.
5. The store mode is released after the store function is executed or when the state of the hook switch changes.
Repertory Dialing
OFF HOOK , (or ON HOOK & HFI ill ), Mn
OFF HOOK , (or ON HOOK & HFI ill ), A , Ln
Access Pause
OFF HOOK , (or ON HOOK & HFI :1 ), D1 , D2 , R/P , D3 ,, Dn

1. The pause function can be stored as a digit in memory.

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- 2. The pause function is executed in normal dialing, redial dialing, or memory dialing.
- 3. A detailed timing diagram for the pause function is shown in Figure 4.

# Pulse-to-tone (\*/T) OFF HOOK , (or ON HOOK & HFI :1 ), D1 , D2 , ..., Dn , \*/T , D1' , D2' , ..., Dn'

1. If the mode switch is set to pulse mode, then the output signal will be:

D1, D2,, Dn, Paus	se (3.6 sec.), D1', D2',, Dn'
(Pulse)	(Tone )

The pause time will be added in all versions except for the W91354AN.

2. If the mode switch is set to tone mode, then the output signal will be:

D1, D2, ..., Dn, \*, D1', D2', ..., Dn' (Tone) (Tone)

- 3. The dialer remains in tone mode when the digits have been dialed out and can be reset to pulse mode only by going on-hook.
- 4. The pulse-to-tone function timing diagram is shown in Figure 5(a, b).

#### Flash



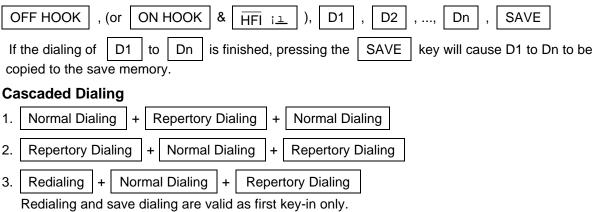
1. Fn = F1, ..., F4

2. The dialer will execute a flash break time of 600 mS (F1), 300 mS (F2), 73 mS (F3), or 100 mS (F4).

In each case the flash pause time is 1.0 sec. before the next digit is dialed out.

- 3. Flash key cannot be stored as a digit in memory, and it has first priority among keyboard functions.
- 4. The system will return to the initial state after the flash pause time is finished.
- 5. The flash function timing diagram is shown in Figure 6.

#### Save





#### **ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	RATING	UNIT
DC Supply Voltage	Vdd-Vss	-0.3 to +7.0	V
	VIL	Vss -0.3	V
Input/Output Voltage	Vih	Vdd +0.3	V
	Vol	Vss -0.3	V
	Vон	Vdd +0.3	V
Power Dissipation	PD	120	mW
Operation Temperature	Topr	-20 to +70	°C
Storage Temperature	Tstg	-55 to +150	°C

Note: Exposure to conditions beyond those listed under Absolute Maximum Ratings may adversely affect the life and reliability of the device.

#### **DC CHARACTERISTICS**

(VDD–Vss = 2.5V, Fosc. = 3.579545 MHz, TA =  $25^{\circ}$  C, All outputs unloaded)

PARAMETER	SYM.	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Operating Voltage	Vdd	-	2.0	-	5.5	V
Operating Current	IOP	Tone, Unloaded	-	0.4	0.6	mA
		Pulse, Unloaded	-	0.2	0.4	
Standby Current	ISB	HKS = Vss, No load & No key entry	-	-	15	μΑ
Memory Retention Current	Imr	$\overline{\text{HKS}}$ = VDD, VDD = 1.0V	-	-	0.2	μΑ
DTMF Output Voltage	νто	Row group, $RL = 5 K\Omega$	130	150	170	mVrms
Pre-emphasis	-	Col/Row, VDD = 2.0 to 5.5V	1	2	3	dB
DTMF Distortion	THD	RL = 5 KΩ, VDD = 2.0 to 5.5V	-	-30	-23	dB
DTMF Output DC Level	VTDC	RL = 5 KΩ, VDD = 2.0 to 5.5V	1.0	-	3.0	V
DTMF Output Sink Current	I⊤∟	VTO = 0.5V	0.2	-	-	mA
DP Output Sink Current	IPL	VPO = 0.5V	0.5	-	-	mA
T/P MUTE Output Sink Current	IML	VMO = 0.5V	0.5	-	-	mA
H/P Mute Output	Інрн	VHPH = 2.0V	0.5	-	-	mA
Drive/Sink Current	Ihpl	VHPL = 0.5V	0.5	-	-	mA



DC Characteristics, continued

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT
HFO Drive/Sink Current	Інғн	VHFH = 2.0V	0.5	-	-	mA
	IHFL	VHFL = 0.5V	0.5	-	-	mA
Keypad Input Drive Current	Ikd	VI = 0.0V	30	-	-	μA
Keypad Input Sink Current	Iĸs	VI = 2.5V	200	400	-	μA
HKS I/P Pull-high Resistor	Rнк	-	-	300	-	KΩ
Keypad Resistance	Rк	-	-	-	5.0	KΩ

#### **AC CHARACTERISTICS**

(VDD-Vss = 2.5V, Fosc. = 3.579545 MHz, TA = 25° C, All outputs unloaded)

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Key-in Debounce	Ткір	-	-	20	-	mS
Key Release Debounce	Tkrd	-	-	20	-	mS
On-hook Debounce	Тонр	-	-	150	-	mS
Pre-digit Pause <sup>1</sup>	TPDP1	Mode = VDD	-	40	-	mS
	10 ppS	Mode = Floating	-	33.3	-	
Pre-digit Pause <sup>2</sup>	TPDP2	Mode = VDD	-	20	-	mS
	20 ppS	Mode = Floating	-	16.7	-	
Interdigit Pause	TIDP	10 ppS	-	800	-	mS
(Auto Dialing)		20 ppS	-	500	-	
Make/Break Ratio	M/B	Mode = VDD	-	40:60	-	%
		Mode = Floating	-	33.3:66.7	-	
Tone Output Duration	Ttd	Auto dialing	-	93	-	mS
		W91354AN Only	-	87	-	
Intertone Pause	Titp	Auto dialing	-	93	-	mS
		W91354AN Only	-	87	-	
		F1	-	600	-	
Flash Break Time	Tfb	F2	-	300	-	mS
		F3		73		
		F4	-	100	-	
Flash Pause Time	TFP	F1, F2, F3, F4	-	1.0	-	S
Pause Time	Тр	R/P	-	3.6	-	S

Notes:

1. Crystal parameters suggested for proper operation are Rs<100 ohms, Lm = 96 mH, Cm = 0.02 pF, Cn = 5 pF, Cl = 18 pF, Fosc.= 3.579545 MHz  $\pm$  0.02%.

2. Crystal oscillator accuracy directly affects these times.



#### TIMING WAVEFORMS

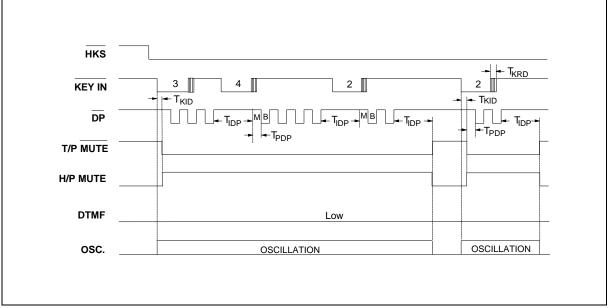


Figure 1(a). Normal Dialing Timing Diagram

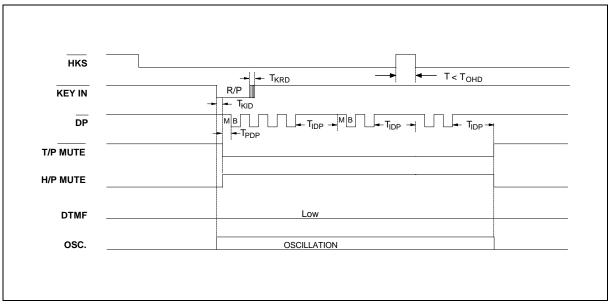


Figure 1(b) Pulse Mode Auto Dialing Timing Diagram



Timing Waveforms, continued

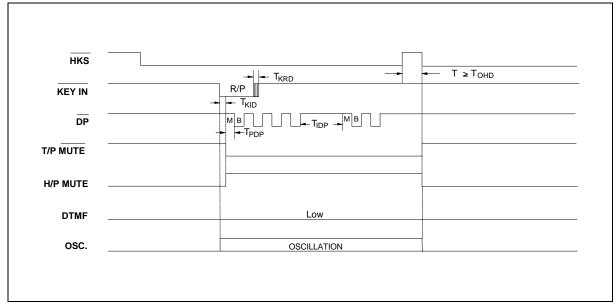


Figure 1(c) Pulse Mode Auto Dialing Timing Diagram

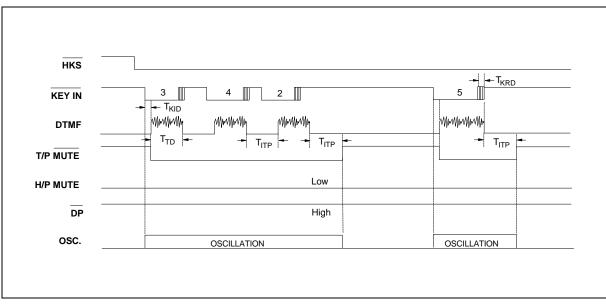


Figure 2(a) Tone Mode Normal Dialing Timing Diagram



Timing Waveforms, continued

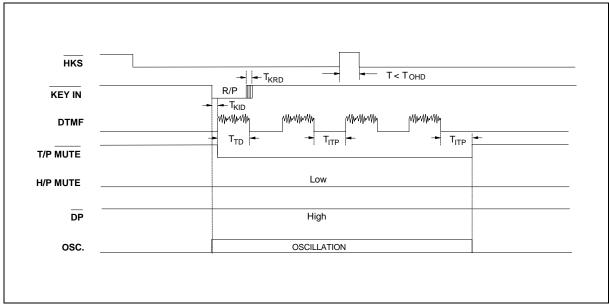


Figure 2(b) Tone Mode Auto Dialing Timing Diagram

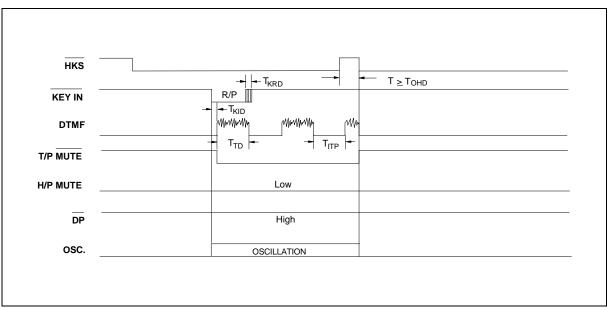


Figure 2(c) Tone Mode Auto Dialing Timing Diagram



Timing Waveforms, continued

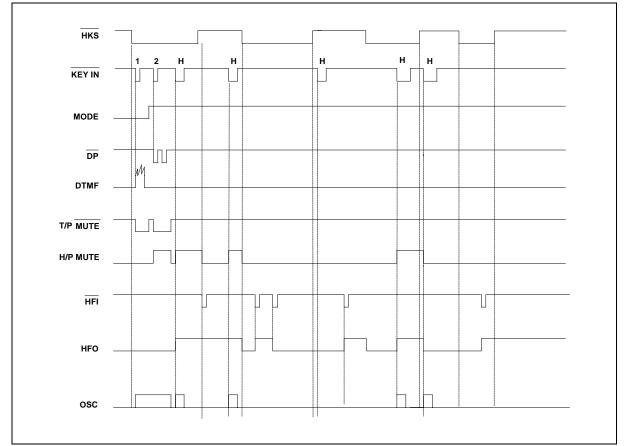


Figure 3. Handfree Function Timing Diagram

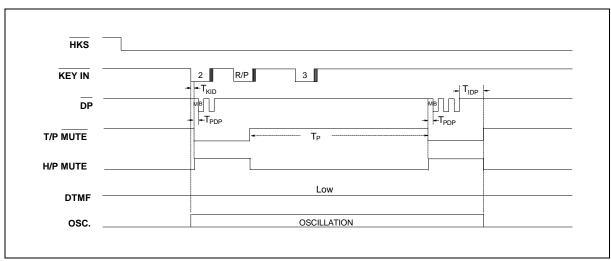


Figure 4. Pause Function Timing Diagram



Timing Waveforms, continued

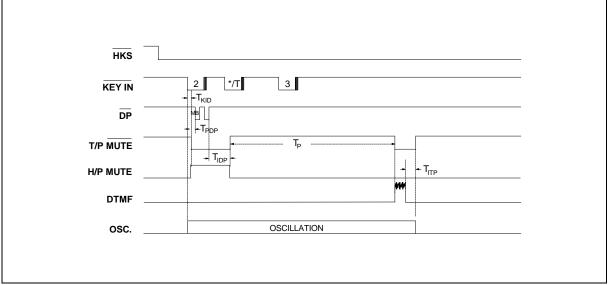


Figure 5(a). Pulse-to-tone Timing Diagram (All Versions Except W91354AN)

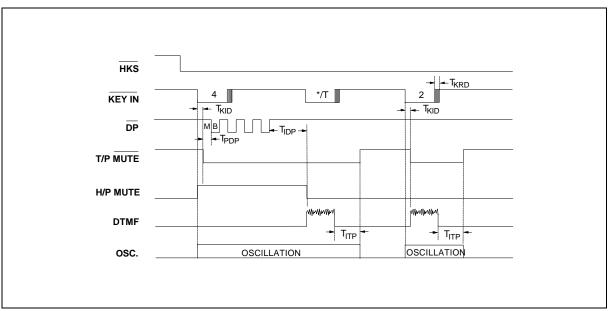


Figure 5(b). Pulse-to-tone Timing Diagram (W91354AN Only)



Timing Waveforms, continued

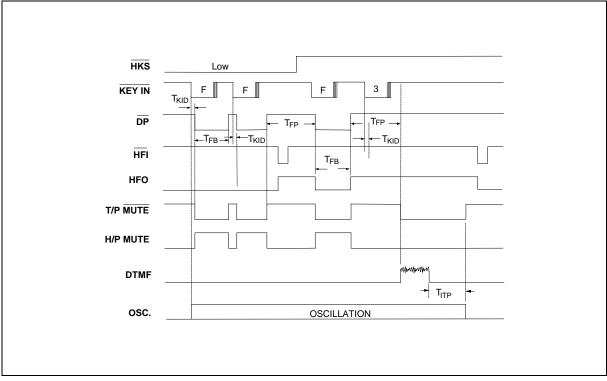


Figure 6. Flash Timing Diagram





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Note: All data and specifications are subject to change without notice.